

AMENDMENTS

Please amend the above-identified application as follows:

In the Claims

In accordance with 37 C.F.R. § 1.121, please substitute the following clean copy text for the pending claims of the same number:

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1 1. (Four Times Amended) An organic light emitting device, comprising:
2 an electrode;
3 a current self-limiting structure comprising conducting regions dispersed in
4 a non-conducting matrix; and
5 an organic stack located between said electrode and said current
6 self-limiting structure.

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1 10. (Four Times Amended) A method for increasing the reliability of an
2 organic light emitting device, comprising the steps of:
3 forming an organic light emitting device including an organic stack; and
4 incorporating a current self-limiting structure comprising conducting
5 regions dispersed in a non-conducting matrix within said organic light emitting device.

Please add the following new claims:

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1 29. The device as defined in claim 1, wherein the current self-limiting structure
2 is a ceramic material and the matrix is a photoresist material.

1 30. The device as defined in claim 1, wherein the current self-limiting structure
2 is a ceramic material and the matrix is a polymer.

1 31. The device as defined in claim 1, wherein the current self-limiting structure
2 is a polymer composite containing inorganic conducting particles.

1 32. The device as defined in claim 1, wherein the current self-limiting structure
2 is a conductive polymer.

1 33. The method as defined in claim 10, wherein the current self-limiting
2 structure is formed using a ceramic material and the matrix is formed using a photoresist
3 material.

1 34. The method as defined in claim 10, wherein the current self-limiting
2 structure is formed using a ceramic material and the matrix is formed using a polymer.

1 35. The method as defined in claim 10, wherein the current self-limiting
2 structure is formed using a polymer composite containing inorganic conducting particles.

1 36. The method as defined in claim 10, wherein the current self-limiting
2 structure is formed using a conductive polymer.
